AN7522

Dual 3-W BTL audio power amplifier

■ Overview

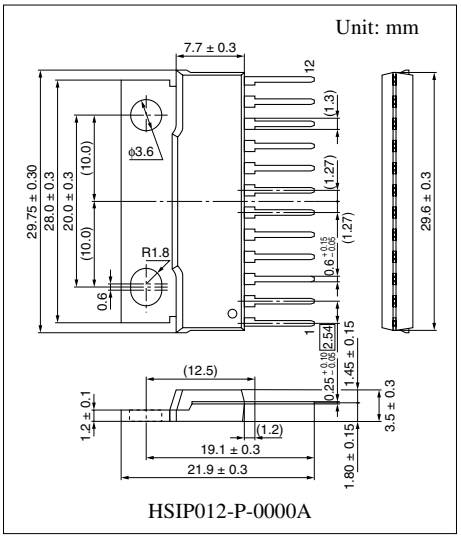
AN7522 is an audio power amplifier IC for the stereo system. In the BTL (balanced transformerless) method, fewer external parts and easier design for applications are required.

■ Features

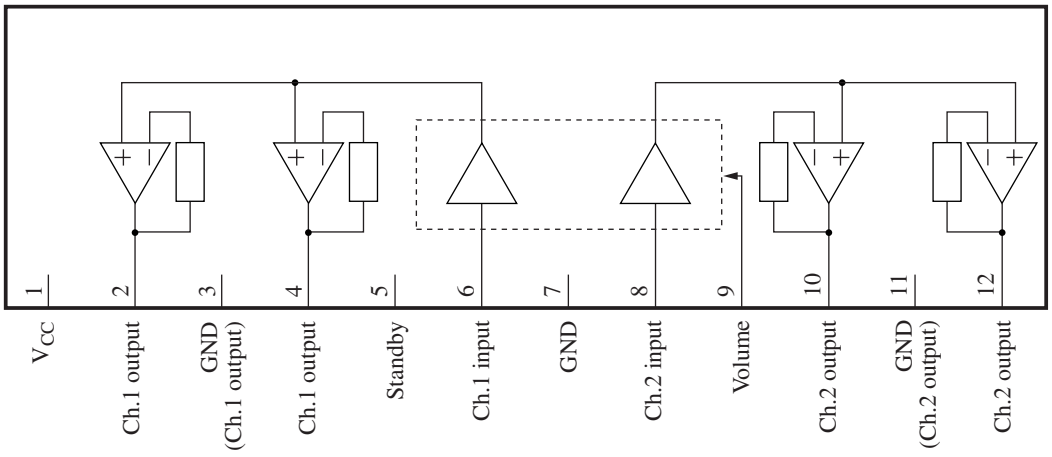
- 3-W output (8 Ω) with supply voltage of 8 V
- On-chip standby function
- On-chip volume function

■ Applications

- Televisions, audio equipment, personal computers, and active speakers



■ Block Diagram



■ Pin Descriptions

Pin No.	Descriptions	Pin No.	Descriptions
1	Supply voltage	7	Ground (input)
2	Ch.1 + output	8	Ch.2 input
3	Ground (output ch.1)	9	Volume (max. volume if this pin is open.)
4	Ch.1 − output	10	Ch.2 − output
5	Standby (standby state if this pin is open.)	11	Ground (output ch.2)
6	Ch.1 input	12	Ch.2 + output

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage *2	V_{CC}	14	V
Supply current	I_{CC}	2.0	A
Power dissipation *3	P_D	1.92	W
Operating ambient temperature *1	T_{opr}	−25 to +70	°C
Storage temperature *1	T_{stg}	−55 to +150	°C

Note) ∗1: Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.

∗2: At no signal.

∗3: The power dissipation shown is the value for T_a = 70°C.

■ Recommended Operating Range

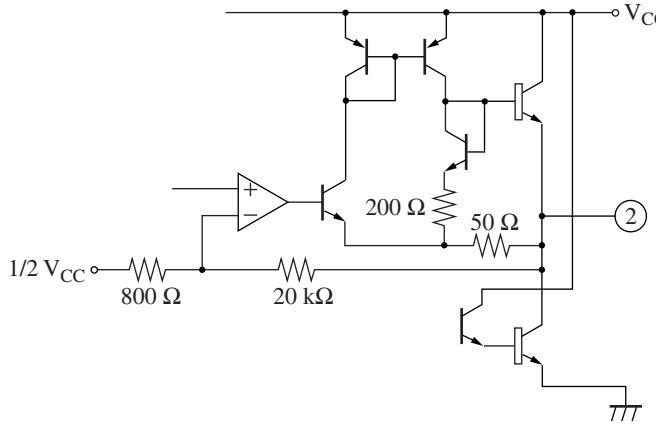
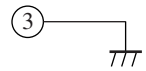
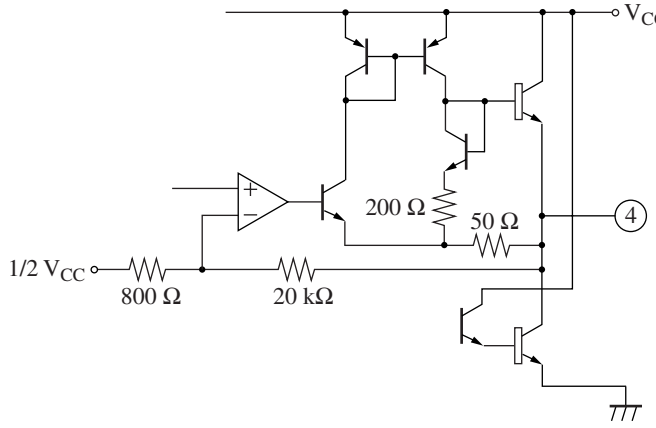
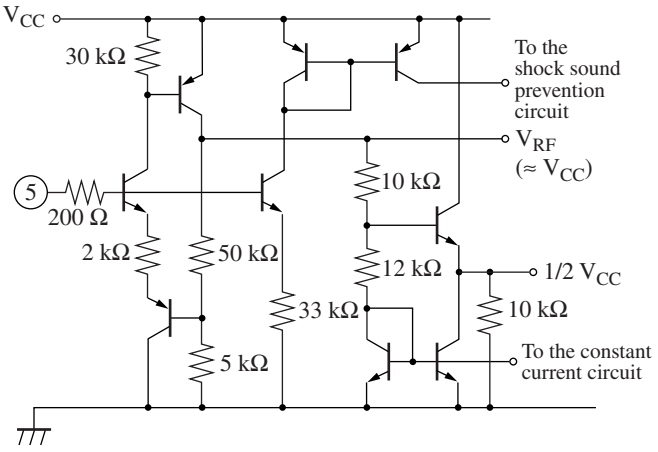
Parameter	Symbol	Range	Unit
Supply voltage	V_{CC}	3.5 to 13.5	V

■ Electrical Characteristics at V_{CC} = 8.0 V, R_L = 8 Ω, f = 1 kHz, T_a = 25°C ± 2°C

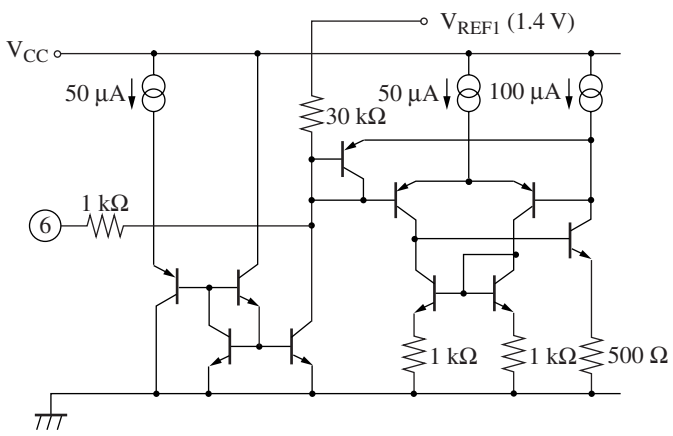
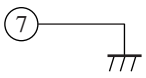
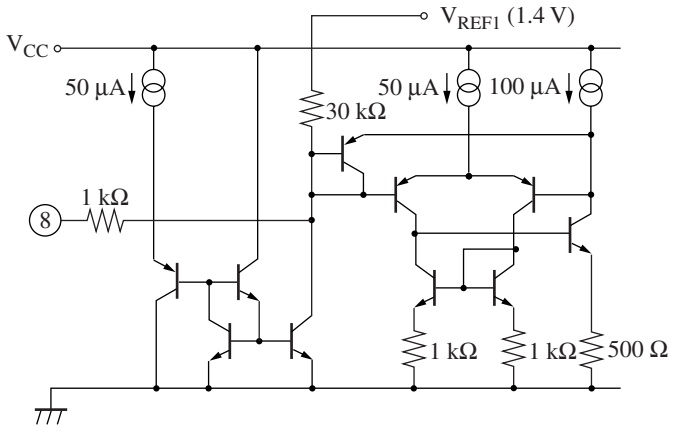
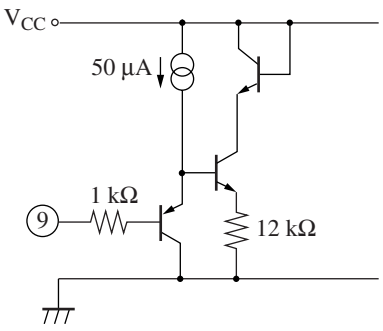
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Quiescent circuit current	I_{CQ}	V_{IN} = 0 mV, Vol. = 0 V	—	45	100	mA
Standby current	I_{STB}	V_{IN} = 0 mV, Vol. = 0 V	—	1	10	µA
Output noise voltage *	V_{NO}	R_g = 10 kΩ, Vol. = 0 V	—	0.10	0.4	mV[rms]
Voltage gain	G_V	P_O = 0.5 W, Vol. = 1.25 V	31	33	35	dB
Total harmonic distortion	THD	P_O = 0.5 W, Vol. = 1.25 V	—	0.10	0.5	%
Maximum output power	P_{O1}	THD = 10%, Vol. = 1.25 V	2.4	3.0	—	W
Ripple rejection ratio *	RR	R_g = 10 kΩ, Vol. = 0 V, V_R = 1 V[rms], f_R = 120 Hz	30	50	—	dB
Output offset voltage	V_{OFF}	R_g = 10 kΩ, Vol. = 0 V	−250	0	250	mV
Volume attenuation rate *	Att	P_O = 0.5 W, Vol. = 0 V	70	85	—	dB
Channel balance 1	CB1	P_O = 0.5 W, Vol. = 1.25 V	−1	0	1	dB
Channel balance 2	CB2	P_O = 0.5 W, Vol. = 0.6 V	−3	0	3	dB
Intermediate voltage gain	G_{VM}	P_O = 0.5 W, Vol. = 0.6 V	20.5	23.5	26.5	dB
Channel crosstalk	CT	P_O = 0.5 W, Vol. = 1.25 V	40	55	—	dB

Note) ∗: In measuring, the filter for the range of 15 Hz to 30 kHz (12 dB/OCT) is used.

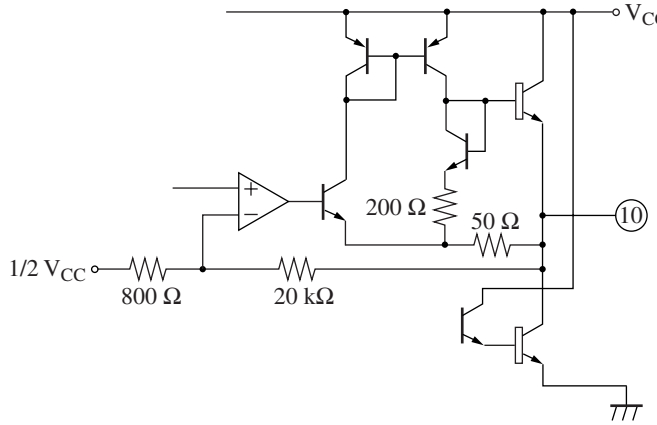
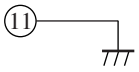
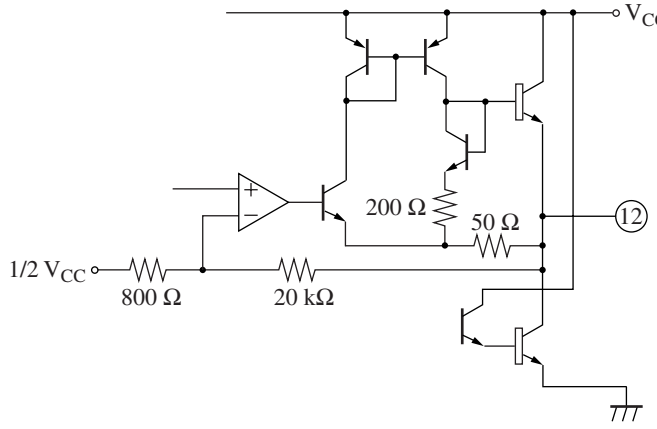
■ Terminal Equivalent Circuits

Pin No.	Pin name	Equivalent circuit	Voltage
1	V_{CC}	—	5.0 V
2	Ch.1 + output pin		2.15 V
3	GND		0 V
4	Ch.1 – output pin		2.15 V
5	Standby pin		5 V

■ Terminal Equivalent Circuits (continued)

Pin No.	Pin name	Equivalent circuit	Voltage
6	Ch.1 input pin		0 mV to 10 mV
7	GND		0 V
8	Ch.2 input pin		0 mV to 10 mV
9	Volume pin		—

■ Terminal Equivalent Circuits (continued)

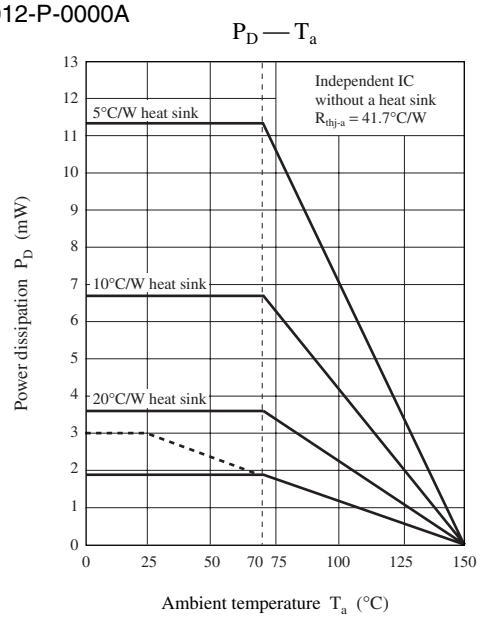
Pin No.	Pin name	Equivalent circuit	Voltage
10	Ch.2 – output pin		2.15 V
11	GND		0 V
12	Ch.2 + output pin		2.15 V

■ Usage Notes

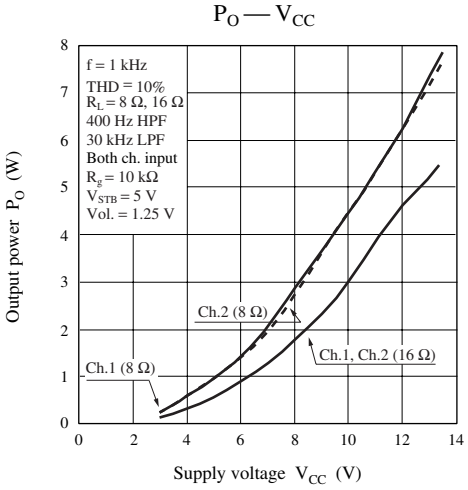
- Please avoid the short-circuits to V_{CC} , ground, or load short-circuit.
- Please connect the cooling fin with the GND potential.
- The thermal shutdown circuit operates at about T_j = 150°C. However, the thermal shutdown circuit is reset automatically if the temperature drops.
- Please carefully design the heat radiation especially when you take out high power at high V_{CC} .
- Please connect only the ground of signal with the signal GND of the amplifier in the previous stage.

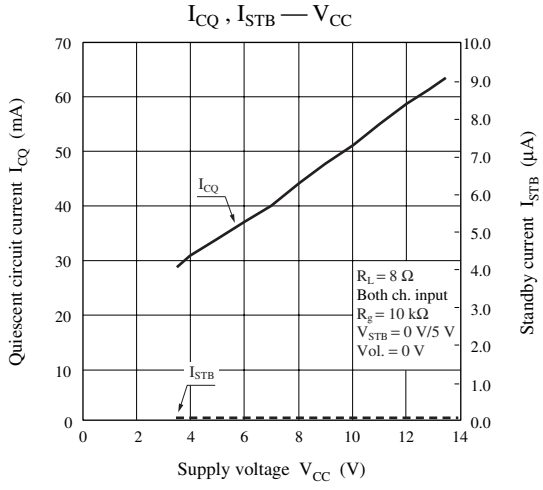
■ Technical Data

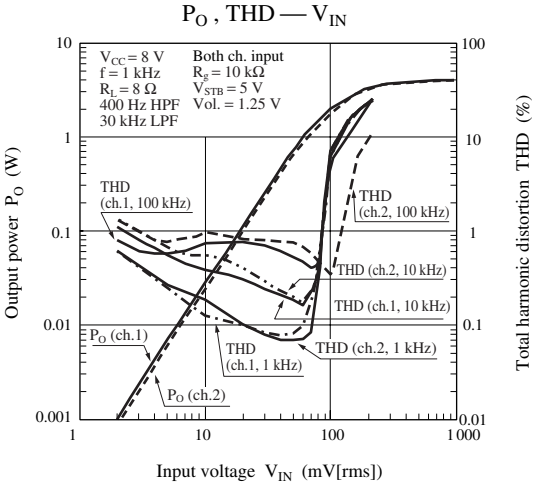
• P_D — T_a curves of HSIP012-P-0000A

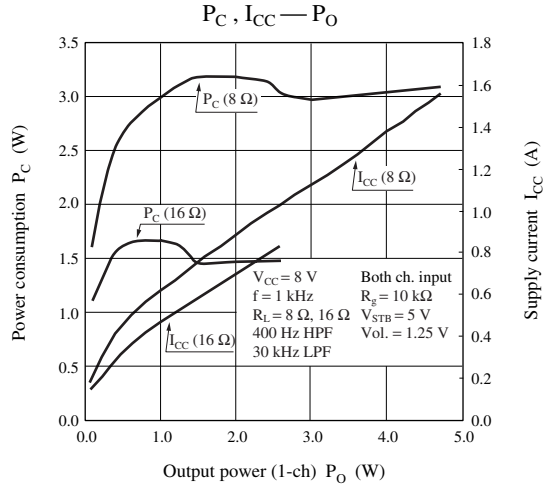


• Main characteristics





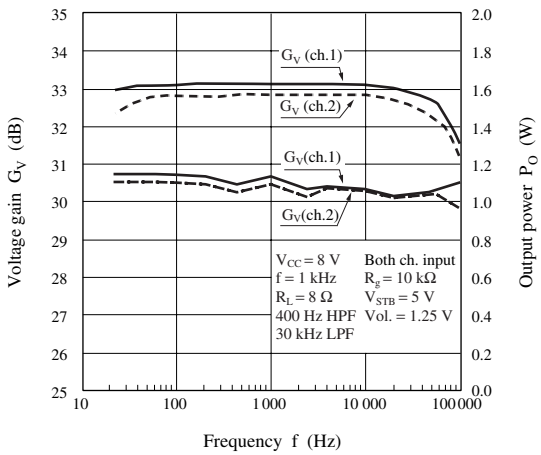




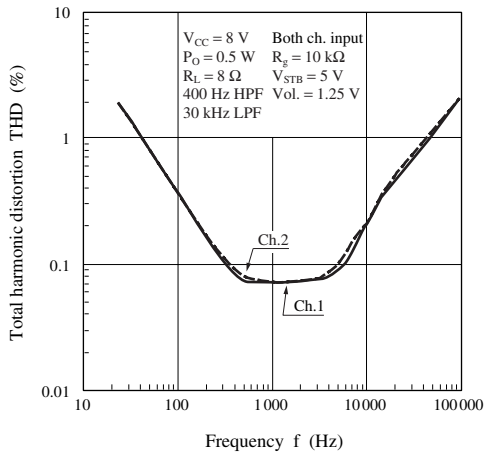
■ Technical Data (continued)

• Main characteristics (continued)

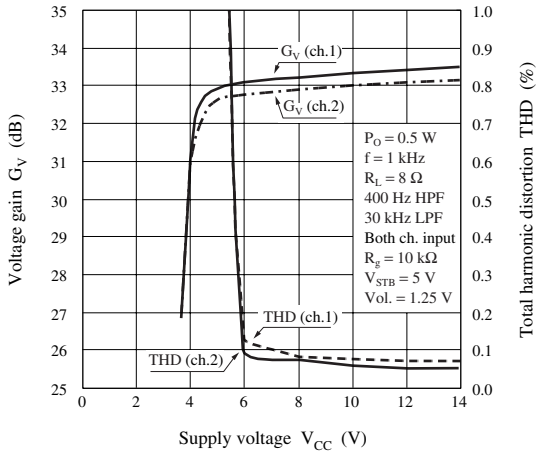
G_V , P_O — f



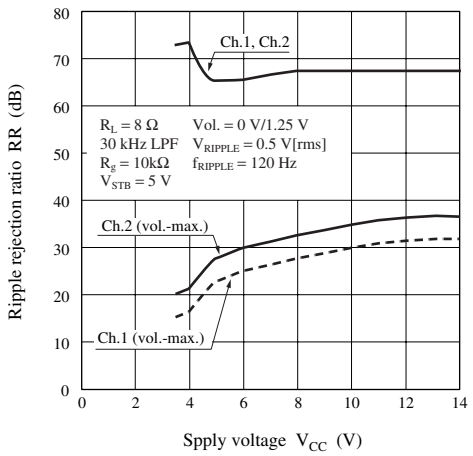
THD — f



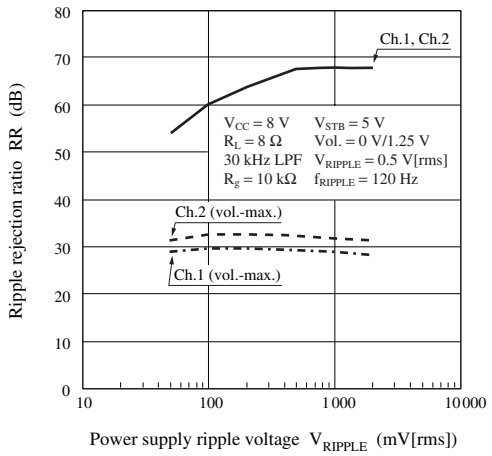
G_V , THD — V_{CC}



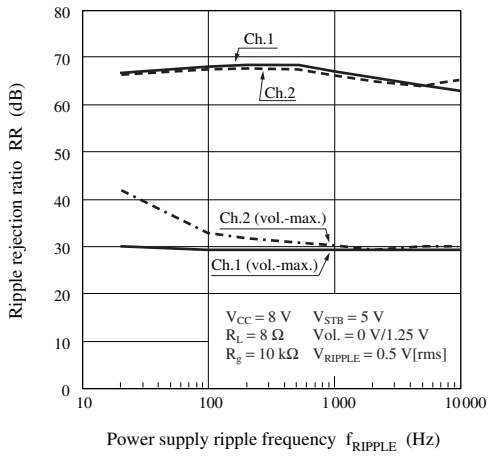
RR — V_{CC}



RR — V_{RIPPLE}



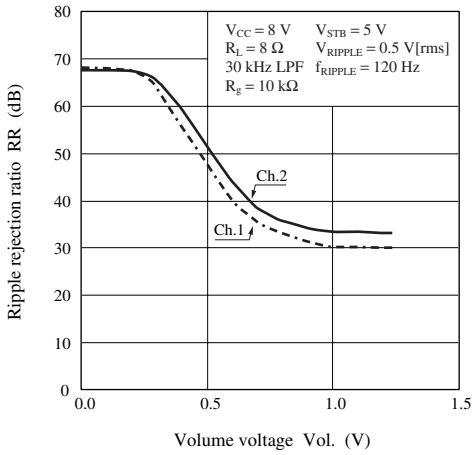
RR — f_{RIPPLE}



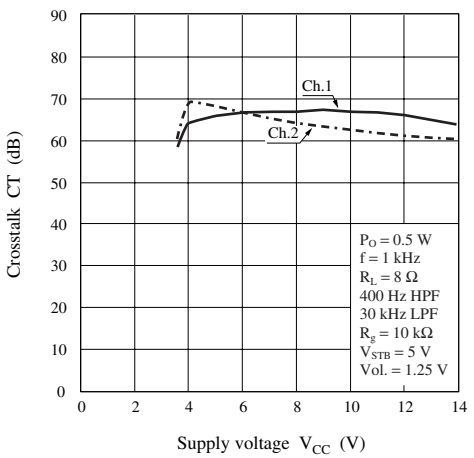
■ Technical Data (continued)

• Main characteristics (continued)

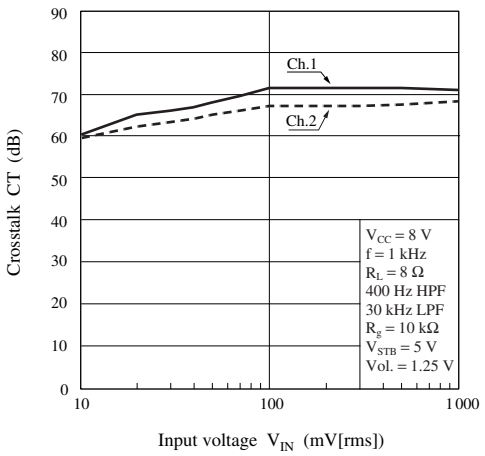
RR — Vol.



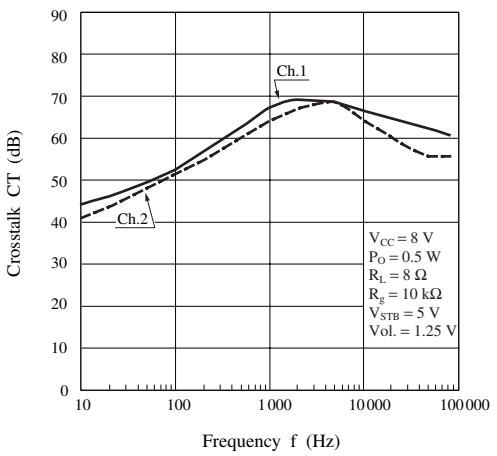
CT — V_{CC}



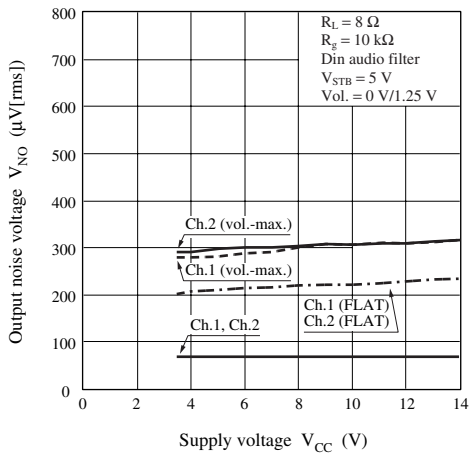
CT — V_{IN}



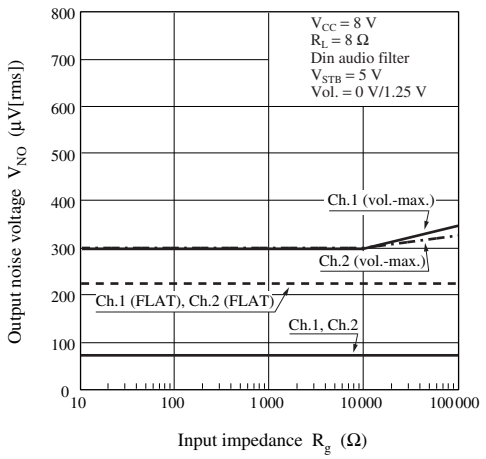
CT — f



V_{NO} — V_{CC}



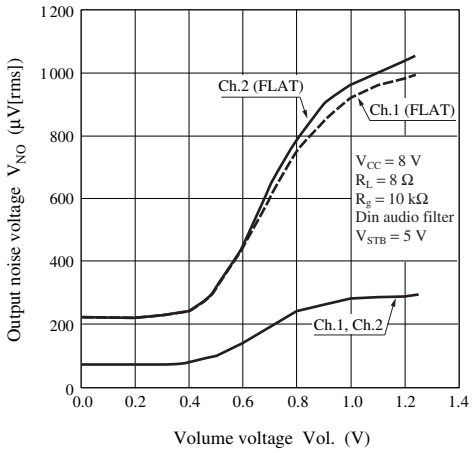
V_{NO} — R_g



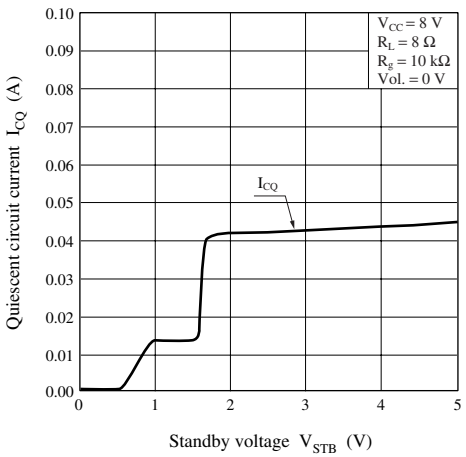
■ Technical Data (continued)

• Main characteristics (continued)

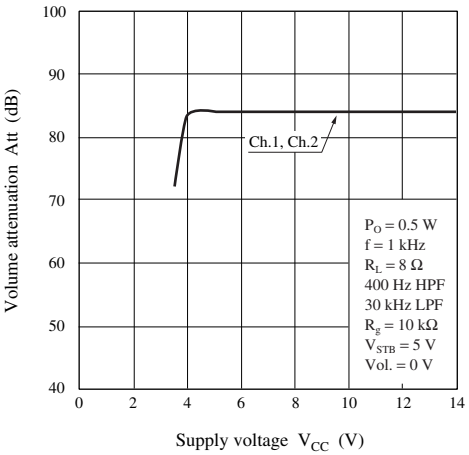
V_{NO} — Vol.



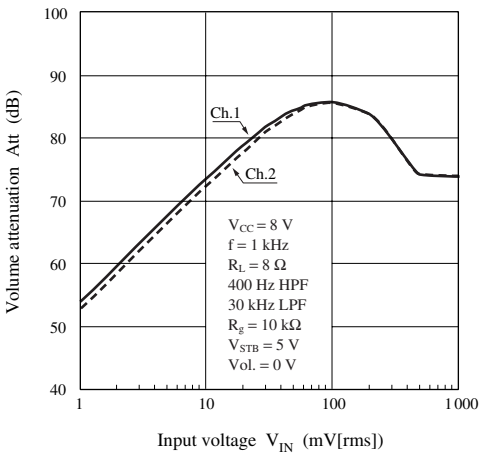
I_{CQ} — V_{STB}



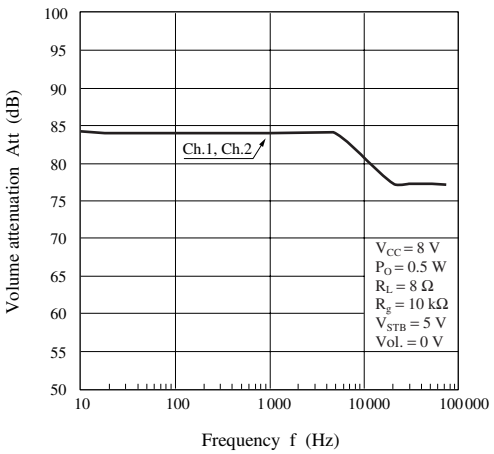
Att — V_{CC}



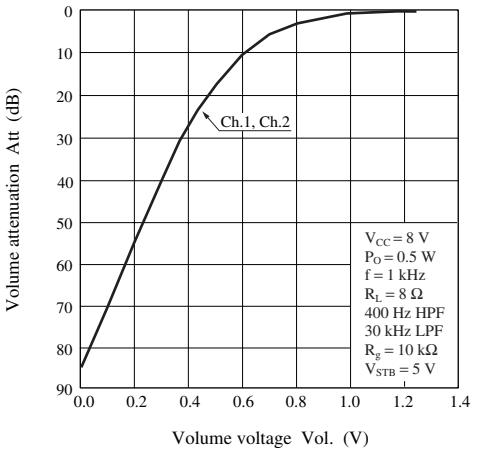
Att — V_{IN}



Att — f



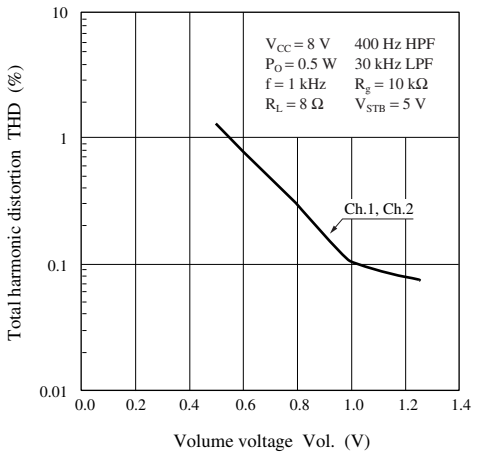
Att — Vol.



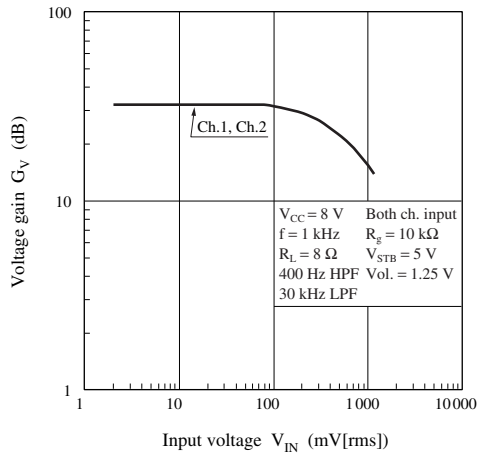
■ Technical Data (continued)

• Main characteristics (continued)

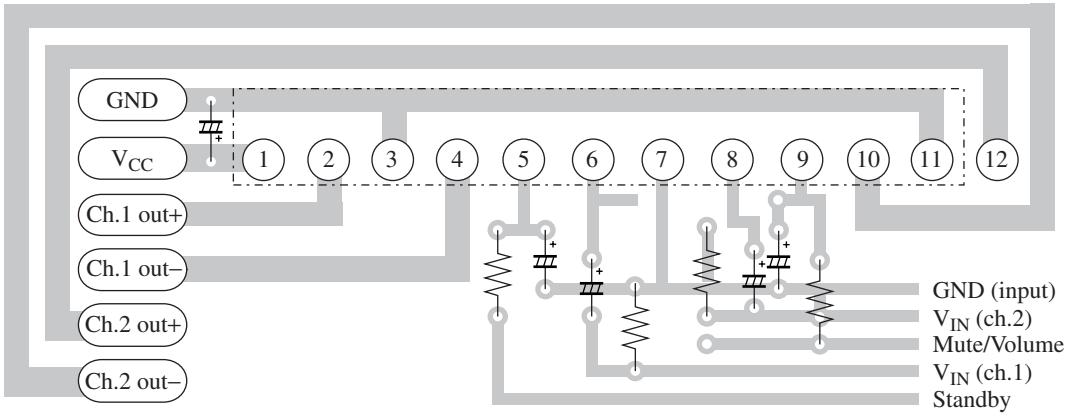
THD — Vol.



G_V — V_{IN}



• Example of PCB pattern



■ Application Circuit Example